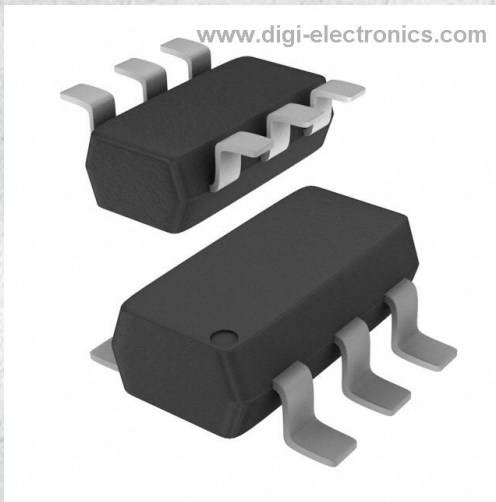


# CM1213A-04SO Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	CM1213A-04SO-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	CM1213A-04SO
Description	TVS DIODE 3.3VWM 10VC SC74
Detailed Description	10V (Typ) Clamp 1A (8/20 $\mu$ s) Ipp Tvs Diode Surface Mount SC-74

This model CM1213A-04SO is available at DiGi Electronics.

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## Purchase and inquiry

Manufacturer Product Number:

CM1213A-0450

Series:

-

Type:

Steering (Rail to Rail)

Voltage - Reverse Standoff (Typ):

3.3V

Voltage - Clamping (Max) @ Ipp:

10V (Typ)

Power - Peak Pulse:

-

Applications:

General Purpose

Operating Temperature:

-40°C ~ 85°C (TA)

Package / Case:

SC-74, SOT-457

Base Product Number:

CM1213

Manufacturer:

onsemi

Product Status:

Active

Unidirectional Channels:

4

Voltage - Breakdown (Min):

6V

Current - Peak Pulse (10/1000µs):

1A (8/20µs)

Power Line Protection:

Yes

Capacitance @ Frequency:

-

Mounting Type:

Surface Mount

Supplier Device Package:

SC-74

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.10.0080

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

# 4-Channel Low Capacitance ESD Protection Array

## CM1213A-04SO, SZCM1213A-04SO



SC-74  
SO SUFFIX  
CASE 318F

### Product Description

CM1213A-04SO has been designed to provide ESD protection for electronic components or subsystems requiring minimal capacitive loading. This device is ideal for protecting systems with high data and clock rates or for circuits requiring low capacitive loading. Each ESD channel consists of a pair of diodes in series which steer the positive or negative ESD current pulse to either the positive ( $V_P$ ) or negative ( $V_N$ ) supply rail. A Zener diode is embedded between  $V_P$  and  $V_N$ , offering two advantages. First, it protects the  $V_{CC}$  rail against ESD strikes, and second, it eliminates the need for a bypass capacitor that would otherwise be needed for absorbing positive ESD strikes to ground. This device will protect against ESD pulses up to 8 kV per the IEC 61000-4-2 standard.

This device is particularly well-suited for protecting systems using high-speed ports such as USB 2.0, IEEE1394 (Firewire<sup>®</sup>, iLink<sup>™</sup>), Serial ATA, DVI, HDMI and corresponding ports in removable storage, digital camcorders, DVD-RW drives and other applications where extremely low loading capacitance with ESD protection are required in a small package footprint.

### Features

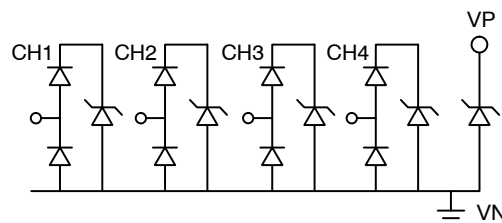
- Four Channels of ESD Protection
- Provides ESD Protection to IEC61000-4-2 Level 4
  - ◆  $\pm 8$  kV Contact Discharge
- Low Channel Input Capacitance of 0.85 pF Typical
- Minimal Capacitance Change with Temperature and Voltage
- Channel Input Capacitance Matching of 0.02 pF Typical is Ideal for Differential Signals
- Zener Diode Protects Supply Rail and Eliminates the Need for External By-pass capacitors
- Each I/O Pin Can Withstand Over 1000 ESD Strikes\*
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and RoHS Compliant

### Applications

- USB2.0 Ports at 480 Mbps in Desktop PCs, Notebooks and Peripherals
- IEEE1394 Firewire<sup>®</sup> Ports at 400 Mbps/800 Mbps
- DVI Ports, HDMI Ports in Notebooks, Set Top Boxes, Digital TVs, LCD Displays
- Serial ATA Ports in Desktop PCs and Hard Disk Drives
- PCI Express Ports
- General Purpose High-Speed Data Line ESD Protection

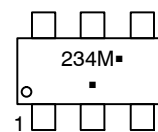
\*Standard test condition is IEC61000-4-2 level 4 test circuit with each pin subjected to  $\pm 8$  kV contact discharge for 1000 pulses. Discharges are timed at 1 second intervals and all 1000 strikes are completed in one continuous test run. The part is then subjected to standard production test to verify that all of the tested parameters are within spec after the 1000 strikes.

### SCHEMATIC



CM1213A-04SO

### MARKING DIAGRAM



234 = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

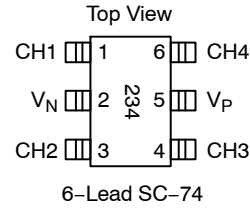
### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
CM1213A-04SO	SC-74 (Pb-Free)	3,000 / Tape & Reel
SZCM1213A-04SO	SC-74 (Pb-Free)	3,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

**CM1213A-04SO, SZCM1213A-04SO****Table 1. PIN DESCRIPTIONS**

Pin	Name	Type	Description
1	CH1	I/O	ESD Channel
2	V <sub>N</sub>	GND	Negative Voltage Supply Rail
3	CH2	I/O	ESD Channel
4	CH3	I/O	ESD Channel
5	V <sub>P</sub>	PWR	Positive Voltage Supply Rail
6	CH4	I/O	ESD Channel

**PACKAGE/PINOUT DIAGRAMS****SPECIFICATIONS****Table 2. ABSOLUTE MAXIMUM RATINGS**

Parameter	Rating	Units
Operating Supply Voltage ( $V_P - V_N$ )	6.0	V
Junction & Storage Temperature Range	-65 to +150	°C
DC Voltage at any channel input	( $V_N - 0.5$ ) to ( $V_P + 0.5$ )	V
Package Power Rating	225	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**Table 3. ELECTRICAL OPERATING CHARACTERISTICS** (Note 1)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V <sub>P</sub>	Operating Supply Voltage ( $V_P - V_N$ )			3.3	5.5	V
I <sub>P</sub>	Operating Supply Current	( $V_P - V_N$ ) = 3.3 V			8.0	μA
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 8 mA; T <sub>A</sub> = 25°C		0.90		V
I <sub>LEAK</sub>	Channel Leakage Current	T <sub>A</sub> = 25°C; V <sub>P</sub> = 5 V, V <sub>N</sub> = 0 V		±0.1	±1.0	μA
C <sub>IN</sub>	Channel Input Capacitance	At 1 MHz, V <sub>IN</sub> = 0 V (Note 2)			2.0	pF
ΔC <sub>I/O</sub>	Channel I/O to I/O Capacitance			1.5		pF
ESD	ESD Protection IEC 61000-4-2 Contact IEC 61000-4-2 Air ISO 10605 330 pF/330 Ω Contact	T <sub>A</sub> = 25°C (Note 3)	±8 ±8 ±8			kV
V <sub>CL</sub>	Channel Clamp Voltage Positive Transients Negative Transients	T <sub>A</sub> = 25°C, I <sub>PP</sub> = 1 A, t <sub>p</sub> = 8/20 μS (Note 2)		+9.9 -1.6		V
R <sub>DYN</sub>	Dynamic Resistance Positive Transients Negative Transients	T <sub>A</sub> = 25°C, I <sub>PP</sub> = 1 A, t <sub>p</sub> = 8/20 μS (Note 2)		0.96 0.5		Ω

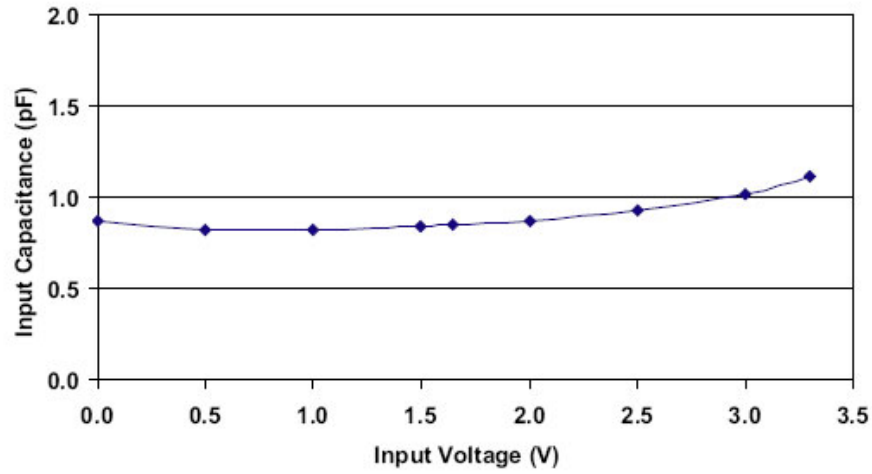
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- All parameters specified at T<sub>A</sub> = -40°C to +85°C unless otherwise noted.
- V<sub>P</sub> = 3.3 V, V<sub>N</sub> grounded.
- These measurements performed with no external capacitor on V<sub>P</sub> (V<sub>P</sub> floating).

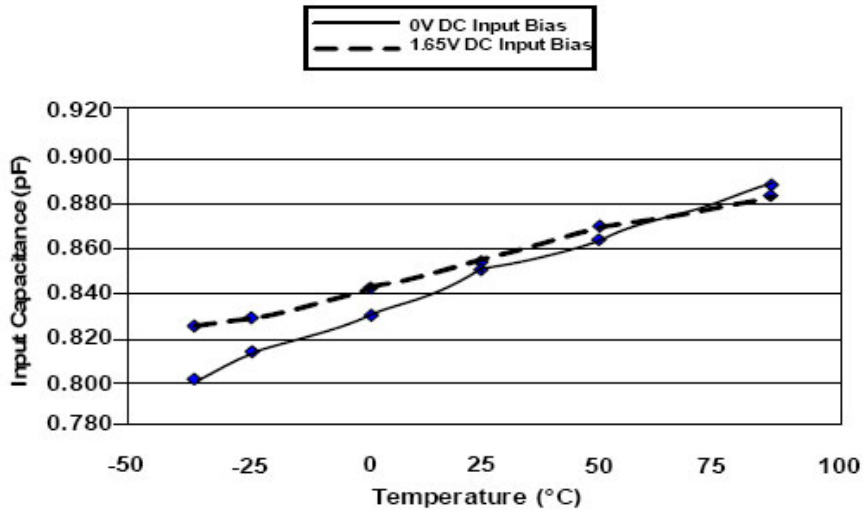
**CM1213A-04SO, SZCM1213A-04SO**

**PERFORMANCE INFORMATION**

**Input Channel Capacitance Performance Curves**



**Figure 1. Typical Variation of  $C_{IN}$  vs.  $V_{IN}$**   
 (f = 1 MHz,  $V_P$  = 3.3 V,  $V_N$  = 0 V, 0.1  $\mu$ F Chip Capacitor between  $V_P$  and  $V_N$ , 25°C)



**Figure 2. Typical Variation of  $C_{IN}$  vs. Temp**  
 (f = 1 MHz,  $V_{IN}$  = 30 mV,  $V_P$  = 3.3 V,  $V_N$  = 0 V, 0.1  $\mu$ F Chip Capacitor between  $V_P$  and  $V_N$ )

**CM1213A-04SO, SZCM1213A-04SO**

**PERFORMANCE INFORMATION (CONT'D)**

Typical Filter Performance (nominal conditions unless specified otherwise, 50 Ohm Environment)

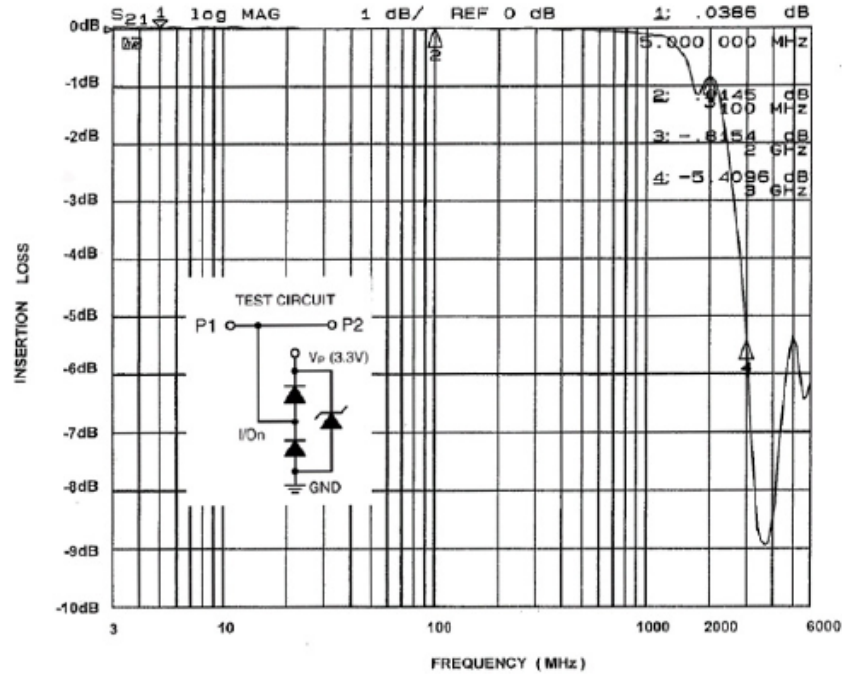


Figure 3. Insertion Loss (S21) vs. Frequency (0 V DC Bias,  $V_p=3.3$  V)

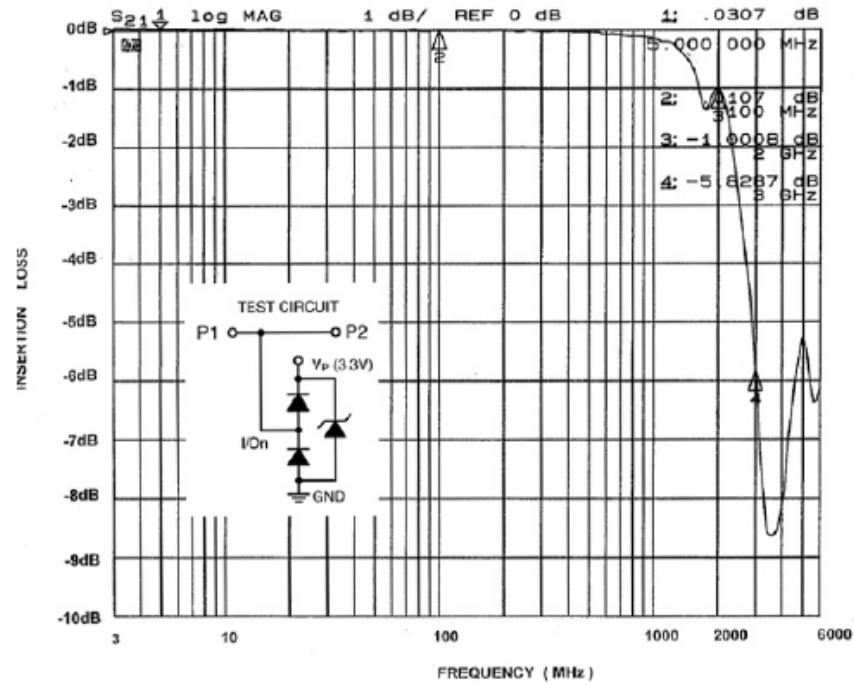


Figure 4. Insertion Loss (S21) vs. Frequency (2.5 V DC Bias,  $V_p=3.3$  V)

**CM1213A-04SO, SZCM1213A-04SO****APPLICATION INFORMATION****Design Considerations**

In order to realize the maximum protection against ESD pulses, care must be taken in the PCB layout to minimize parasitic series inductances on the Supply/Ground rails as well as the signal trace segment between the signal input (typically a connector) and the ESD protection device. Refer to Application of Positive ESD Pulse between Input Channel and Ground, which illustrates an example of a positive ESD pulse striking an input channel. The parasitic series inductance back to the power supply is represented by  $L_1$  and  $L_2$ . The voltage  $V_{CL}$  on the line being protected is:

$$V_{CL} = \text{Fwd Voltage Drop of } D_1 + V_{\text{SUPPLY}} + L_1 \times d(I_{\text{ESD}}) / dt + L_2 \times d(I_{\text{ESD}}) / dt$$

where  $I_{\text{ESD}}$  is the ESD current pulse, and  $V_{\text{SUPPLY}}$  is the positive supply voltage.

An ESD current pulse can rise from zero to its peak value in a very short time. As an example, a level 4 contact discharge per the IEC61000-4-2 standard results in a current pulse that rises from zero to 30 Amps in 1 ns. Here  $d(I_{\text{ESD}})/dt$  can be approximated by  $\Delta I_{\text{ESD}}/\Delta t$ , or  $30/(1 \times 10^{-9})$ . So just 10 nH of series inductance ( $L_1$  and  $L_2$  combined) will lead to a 300 V increment in  $V_{CL}$ !

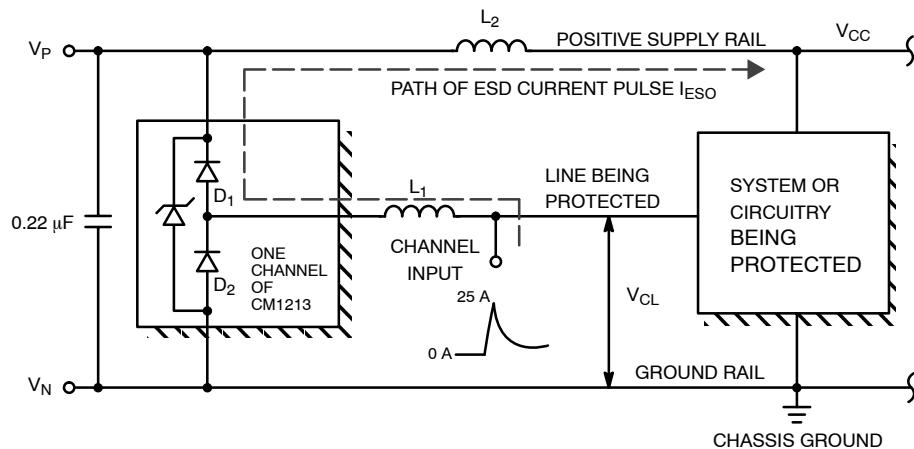
Similarly for negative ESD pulses, parasitic series inductance from the  $V_N$  pin to the ground rail will lead to drastically increased negative voltage on the line being protected.

The CM1213A has an integrated Zener diode between  $V_P$  and  $V_N$ . This greatly reduces the effect of supply rail inductance  $L_2$  on  $V_{CL}$  by clamping  $V_P$  at the breakdown voltage of the Zener diode. However, for the lowest possible  $V_{CL}$ , especially when  $V_P$  is biased at a voltage significantly below the Zener breakdown voltage, it is recommended that a 0.22  $\mu\text{F}$  ceramic chip capacitor be connected between  $V_P$  and the ground plane.

As a general rule, the ESD Protection Array should be located as close as possible to the point of entry of expected electrostatic discharges. The power supply bypass capacitor mentioned above should be as close to the  $V_P$  pin of the Protection Array as possible, with minimum PCB trace lengths to the power supply, ground planes and between the signal input and the ESD device to minimize stray series inductance.

**Additional Information**

See also ON Semiconductor Application Note "Design Considerations for ESD Protection", in the Applications section.



**Figure 5. Application of Positive ESD Pulse between Input Channel and Ground**



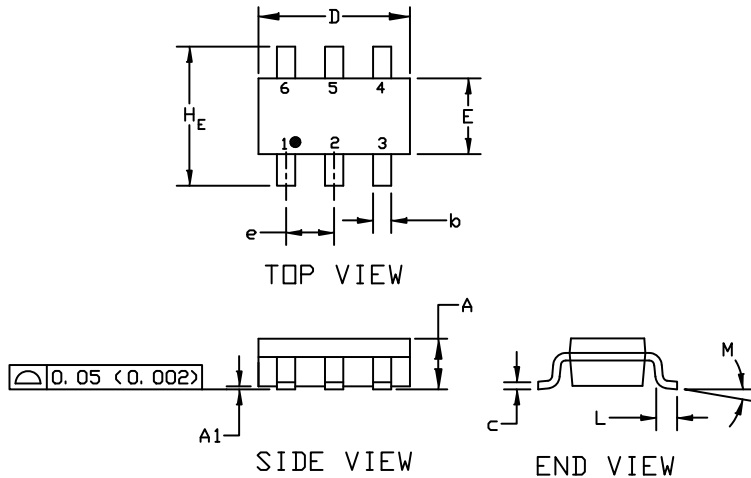
**MECHANICAL CASE OUTLINE  
PACKAGE DIMENSIONS**



SCALE 2:1

**SC-74  
CASE 318F  
ISSUE P**

DATE 07 OCT 2021

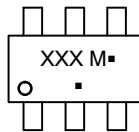


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
2. CONTROLLING DIMENSION: INCHES
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
H <sub>E</sub>	2.50	2.75	3.00	0.099	0.108	0.118
L	0.20	0.40	0.60	0.008	0.016	0.024
M	0°	---	10°	0°	---	10°

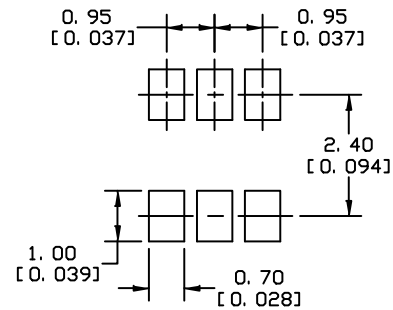
**GENERIC MARKING DIAGRAM\***



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

**SOLDERING FOOTPRINT**

- |  |   |  |   |  |  |
|--|---|--|---|--|--|
| <p><b>STYLE 1:</b><br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. CATHODE<br/>5. ANODE<br/>6. CATHODE</p>     | <p><b>STYLE 2:</b><br/>PIN 1. NO CONNECTION<br/>2. COLLECTOR<br/>3. EMITTER<br/>4. NO CONNECTION<br/>5. COLLECTOR<br/>6. BASE</p> | <p><b>STYLE 3:</b><br/>PIN 1. EMITTER 1<br/>2. BASE 1<br/>3. COLLECTOR 2<br/>4. EMITTER 2<br/>5. BASE 2<br/>6. COLLECTOR 1</p> | <p><b>STYLE 4:</b><br/>PIN 1. COLLECTOR 2<br/>2. EMITTER 1/EMITTER 2<br/>3. COLLECTOR 1<br/>4. EMITTER 3<br/>5. BASE 1/BASE 2/COLLECTOR 3<br/>6. BASE 3</p> | <p><b>STYLE 5:</b><br/>PIN 1. CHANNEL 1<br/>2. ANODE<br/>3. CHANNEL 2<br/>4. CHANNEL 3<br/>5. CATHODE<br/>6. CHANNEL 4</p> | <p><b>STYLE 6:</b><br/>PIN 1. CATHODE<br/>2. ANODE<br/>3. CATHODE<br/>4. CATHODE<br/>5. CATHODE<br/>6. CATHODE</p> |
| <p><b>STYLE 7:</b><br/>PIN 1. SOURCE 1<br/>2. GATE 1<br/>3. DRAIN 2<br/>4. SOURCE 2<br/>5. GATE 2<br/>6. DRAIN 1</p> | <p><b>STYLE 8:</b><br/>PIN 1. EMITTER 1<br/>2. BASE 2<br/>3. COLLECTOR 2<br/>4. EMITTER 2<br/>5. BASE 1<br/>6. COLLECTOR 1</p>    | <p><b>STYLE 9:</b><br/>PIN 1. EMITTER 2<br/>2. BASE 2<br/>3. COLLECTOR 1<br/>4. EMITTER 1<br/>5. BASE 1<br/>6. COLLECTOR 2</p> | <p><b>STYLE 10:</b><br/>PIN 1. ANODE/CATHODE<br/>2. BASE<br/>3. EMITTER<br/>4. COLLECTOR<br/>5. ANODE<br/>6. CATHODE</p>                                    | <p><b>STYLE 11:</b><br/>PIN 1. EMITTER<br/>2. BASE<br/>3. ANODE/CATHODE<br/>4. ANODE<br/>5. CATHODE<br/>6. COLLECTOR</p>   |  |

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<b>DESCRIPTION:</b>	<b>SC-74</b>	<b>PAGE 1 OF 1</b>

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